

## UNITED STATES DEPARTMENT OF COMMERCE

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FIRST NAMED INVENTOR APPLICATION NO. **FILING DATE** ATTORNEY DOCKET NO SHM-00901 YAMAMOTO 11/29/99 09/450,351 **EXAMINER** MMC2/0405 026339 HUTCHINS, WHEELER & DITTMAR **ART UNIT** PAPER NUMBER 101 FEDERAL STREET BOSTON MA 02110 2812 DATE MAILED: 04/05/01

Please find below and/or attached an Office communication concerning this application or proceeding.

**Commissioner of Patents and Trademarks** 

Application No. 09/450,351

Applicant(s)

Yamamoto

Office Action Summary Examiner

H, Jey Tsai

Group Art Unit 2812



Responsive to communication(s) filed on 1/24/01	·
X This action is <b>FINAL</b> .	
Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11; 453 O.G. 213.	
A shortened statutory period for response to this action is set to expision like its longer, from the mailing date of this communication. Failure to result application to become abandoned. (35 U.S.C. § 133). Extensions of 37 CFR 1.136(a).	pond within the period for response will cause the
Disposition of Claims	
	is/are pending in the application.
Of the above, claim(s)	is/are withdrawn from consideration.
☐ Claim(s)	is/are allowed.
	is/are rejected.
☐ Claim(s)	is/are objected to.
☐ Claims	
Application Papers  See the attached Notice of Draftsperson's Patent Drawing Revi The drawing(s) filed on is/are objected to The proposed drawing correction, filed on The specification is objected to by the Examiner. The oath or declaration is objected to by the Examiner.  Priority under 35 U.S.C. § 119	by the Examiner.
<ul> <li>□ Acknowledgement is made of a claim for foreign priority under</li> <li>□ All □ Some* □ None of the CERTIFIED copies of the positive of the</li></ul>	priority documents have been national Bureau (PCT Rule 17.2(a)).
Attachment(s)  Notice of References Cited, PTO-892  Information Disclosure Statement(s), PTO-1449, Paper No(s).  Interview Summary, PTO-413  Notice of Draftsperson's Patent Drawing Review, PTO-948  Notice of Informal Patent Application, PTO-152	
SEE OFFICE ACTION ON THE FOLLOWING PAGES	

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## Claim Rejections - 35 U.S.C. § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-29 stand rejected under 35 U.S.C. 103(a) as being unpatentable over Nishikawa 6,087,261 in view of Tamaru et al. 6,103,566 and Lee et al. 6,010,940, all are previously applied.

The reference(s) teach the features:

Nishikawa substantially discloses a method of forming a capacitor on the semiconductor device, which includes:

forming a tantalum oxide dielectric layer 5, fig. 4B,

treating substrate in the chamber with at least one of a gas containing non-reactive  $\mathrm{NH_3}$  and helium gases flow, col. 9, lines 1+,

heating the substrate in the  $\mathrm{NH_3}$  ambient at about 0.15 torr, fig. 6, col. 9, lines 30+,

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introducing the source gas containing a high melting point metal  $TiCl_4$  to form TiN layer 6.

The difference between the reference(s) and the claims are as follows:

Nishikawa et al. teaches using helium as inert gas.

However, Tamaru et al. teaches using nitrogen gas during the heat treatment process, before introducing NH<sub>3</sub>, then forming metal nitride with high melting metal containing gas in col. 18, lines 27+ and col. 16, lines 20. And, Lee teaches annealing the substrate with NH<sub>3</sub> after forming TiN.

It would have been obvious to one having ordinary skill in the art at the time the invention was made to have modified Nishikawa et al.'s process with nitrogen gas to stabilize the tantalum oxide with heat treating step as suggested by Tamaru et al. because nitrogen does not reoxidize the tantalum oxide.

Applicant's arguments filed Jan. 24, 2001 have been fully considered but they are not persuasive.

Applicant contends that Nishikawa teaches using an oxidizing ambient and not an inert ambient. This is not found to be persuasive because there is not seen an inert ambient in the

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claimed invention, e.g. in claim 1, it reads "with at least one of a gas non-reactive with respect to said metal oxide...".

Nishikawa teaches one of gases is helium gas which is an inert gas, hence is non-reactive with respect to the tantalum oxide layer 5, therefore, it meets the claimed invention. see col. 9, lines 13+,

Applicant contends that Nishikawa teaches introduing He and oxygen prior to the deposition of metal oxide during the a chamber purging step. This is not found to be persuasive because Nishikawa teaches reduction or reoxidation of  $Ta_sO_5$  by introducing oxygen and helium is prevented in col. 9, lines 12+. And, oxygne only react with the carbon or hydrogen in the  $Ta_sO_5$  layer not  $Ta_sO_5$  layer itself. Tamaru et al. also teaches one of inert gases is He, Ar or  $N_2$  with respect to the tantalum oxide and a  $NH_3$  gas and metal source gas  $TiCl_4$  in col. 16, line 15+ and fig. 35.

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is

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not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry of a general nature or clerical matters or relating to the status of this application or proceeding should be directed to the Group customer service whose telephone number is (703) 306-3329 and Fax number (703) 306-5515. Group receptionist telephone number 703-308-0956.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to H. Jey Tsai whose telephone number is (703) 308-1374. The examiner can normally be reached on from 7:00 Am to 4:00 Pm., Monday thru Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling can be reached on (703) 308-3325. The fax phone number for this Group is (703) 305-3431.

hjt 02/16/1

> H. Jey Tsai Primary Examiner

Patent Examining Group 2800